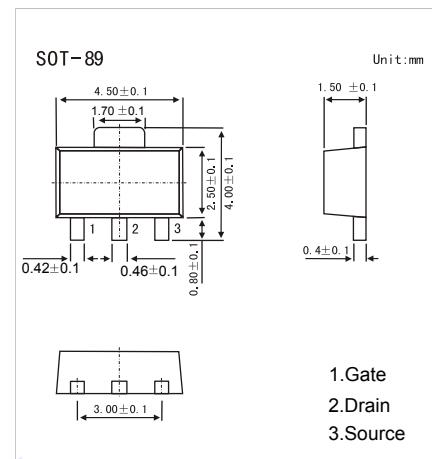
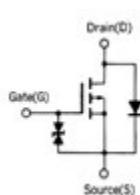


P-Channel MOSFET

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■ Features

- $V_{DS} (V) = -100V$
- $I_D = -1 A (V_{GS} = -10V)$
- $R_{DS(ON)} < 2 \Omega (V_{GS} = -10V)$
- $R_{DS(ON)} < 2.5 \Omega (V_{GS} = -4V)$

■ Absolute Maximum Ratings $T_a = 25^\circ C$

| Parameter | Symbol | Rating | Unit |
|--------------------------------------|-----------|------------|------------|
| Drain-Source Voltage | V_{DS} | -100 | V |
| Gate-Source Voltage | V_{GS} | ± 20 | |
| Continuous Drain Current | I_D | -1 | A |
| Pulsed Drain Current (Note.1) | I_{DM} | -2 | |
| Power Dissipation $T_c = 25^\circ C$ | P_D | 2 | W |
| Junction Temperature | T_J | 150 | $^\circ C$ |
| Junction Storage Temperature Range | T_{stg} | -55 to 150 | |

Note.1: $PW \leq 10 \text{ ms}, \text{duty cycle} \leq 50\%$ ■ Electrical Characteristics $T_a = 25^\circ C$

| Parameter | Symbol | Test Conditions | Min | Typ | Max | Unit |
|-----------------------------------|---------------|---|------|-----|----------|----------|
| Drain-Source Breakdown Voltage | V_{DSS} | $I_D = -250 \mu A, V_{GS} = 0V$ | -100 | | | V |
| Zero Gate Voltage Drain Current | I_{DSS} | $V_{DS} = -100V, V_{GS} = 0V$ | | | -10 | μA |
| Gate-Body leakage current | I_{GSS} | $V_{DS} = 0V, V_{GS} = \pm 20V$ | | | ± 10 | μA |
| Gate to Source Cutoff Voltage | $V_{GS(off)}$ | $V_{GS} = -10V I_D = -1mA$ | -1 | | -3 | V |
| Static Drain-Source On-Resistance | $R_{DS(on)}$ | $V_{GS} = -10V, I_D = -0.5A$ | | | 2 | Ω |
| | | $V_{GS} = -4V, I_D = -0.5A$ | | | 2.5 | |
| Forward Transconductance | g_{FS} | $V_{DS} = -10V, I_D = -0.5A$ | 0.4 | 0.9 | | S |
| Input Capacitance | C_{iss} | $V_{GS} = 0V, V_{DS} = -10V, f = 1MHz$ | | 220 | | pF |
| Output Capacitance | C_{oss} | | | 85 | | |
| Reverse Transfer Capacitance | C_{rss} | | | 8 | | |
| Turn-On Delay Time | $t_{d(on)}$ | $V_{GS(on)} = -10V, I_D = -0.5A, R_L = 50 \Omega, R_G = 10 \Omega, V_{DD} = -25V$ | | 45 | | ns |
| Turn-On Rise Time | t_r | | | 36 | | |
| Turn-Off Delay Time | $t_{d(off)}$ | | | 360 | | |
| Turn-Off Fall Time | t_f | | | 90 | | |

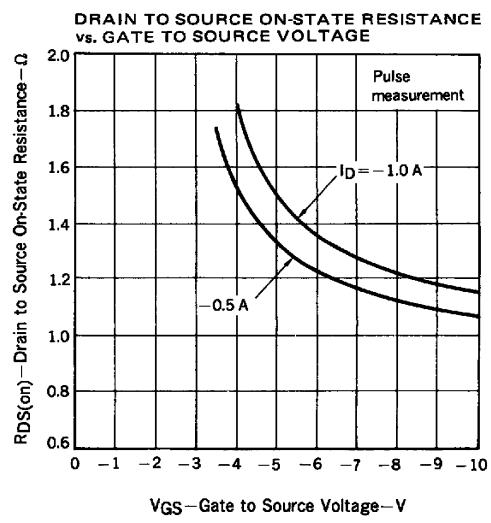
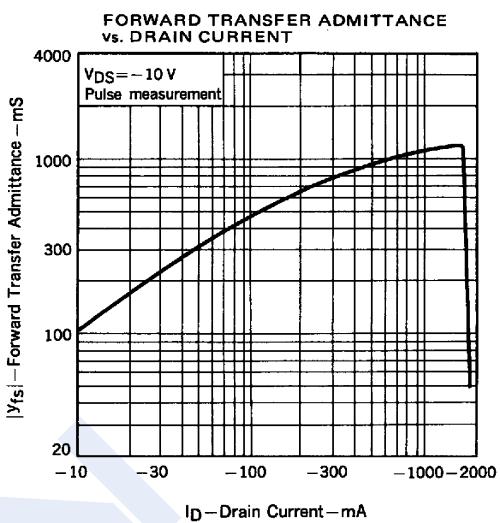
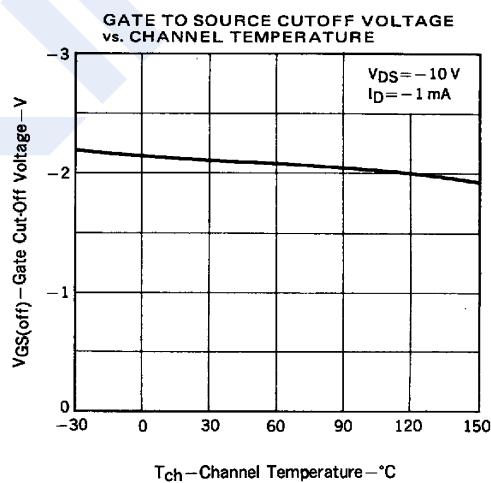
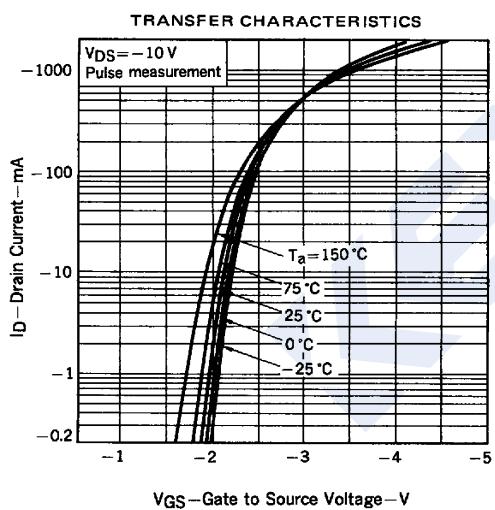
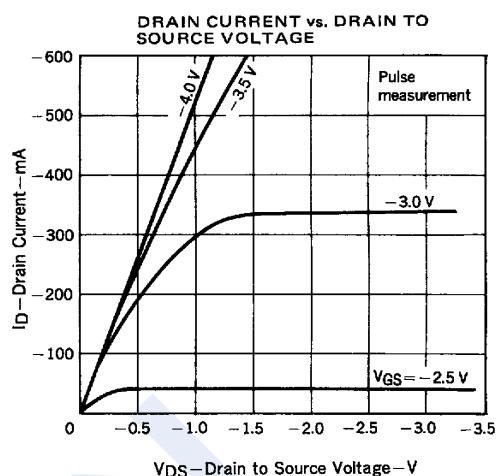
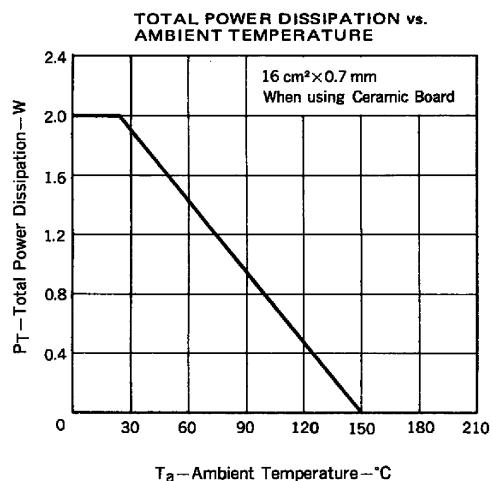
■ Marking

| | |
|---------|----|
| Marking | PC |
|---------|----|

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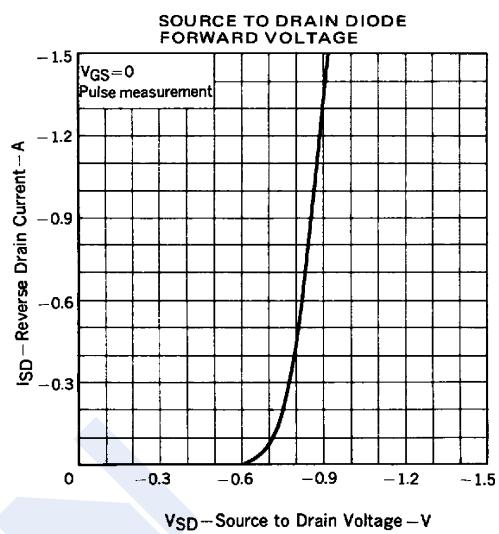
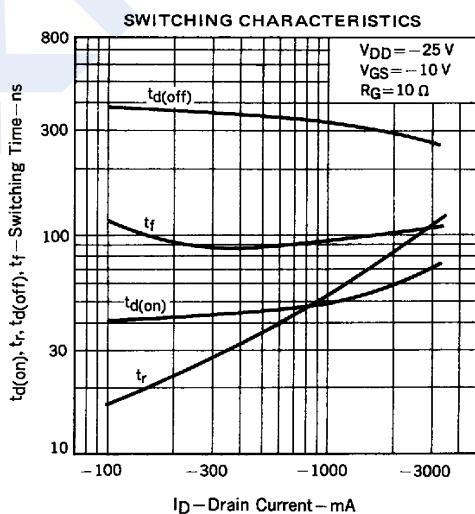
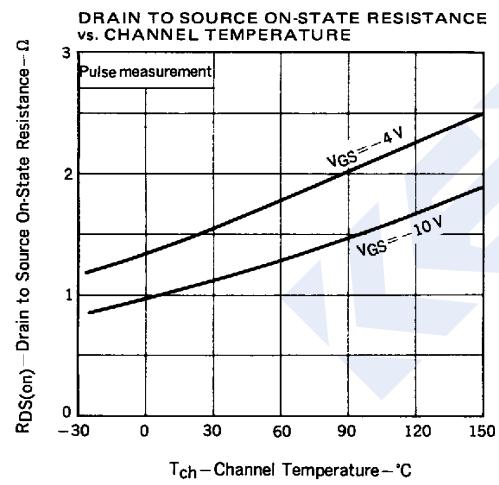
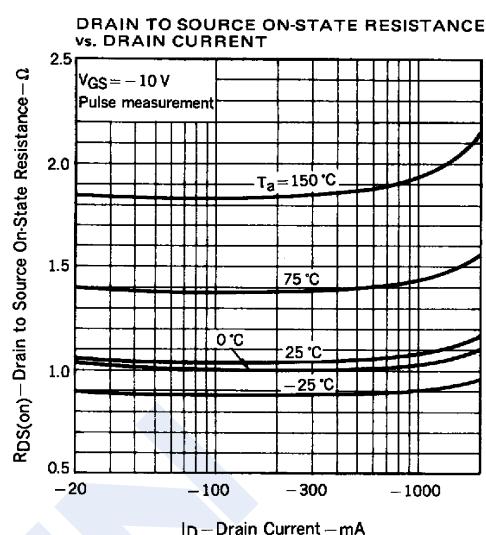
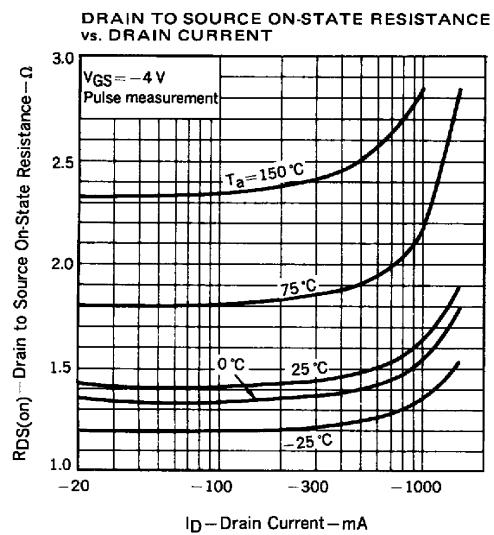
■ Typical Characteristics



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■ Typical Characteristics



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■ Typical Characteristics

